PCI	N Nun	nber:	2	02301280	001	.1			PC	N Date'	February 01, 2023		
Title: Qualify TI Malaysia as an additional Assembly site for select of										t devices			
Cus	stome	er Contact:	PC	IN Manager	_		Dept:	Quality Se	ervic	ccented			
Proposed 1 <sup>st</sup> Ship Date:				May 1, 2	023		Sample r until:	equests a	Mar 03, 2023*				
*Sample requests received after Mar 03, 2023 will not be supported.													
Cha	ange '	Туре:											
$\boxtimes$	Asse	mbly Site				Desi	ign			Wafer Bump Site			
			Data	a Sheet			Wafer Bui	Wafer Bump Material					
Assembly Materials						Part	Part number change 🛛 Wafer Bu				Imp Process		
Mechanical Specification						Test	est Site 🛛 🗌 Wafer Fa			Wafer Fat	b Site		
Packing/Shipping/Labeling						Test	Process			Wafer Fab Materials			
										Wafer Fat	o Process		
	PCN Details												

## Description of Change:

Texas Instruments Incorporated is announcing the qualification of TI Malaysia as an additional Assembly site for devices listed below in the product affected section. Material differences between assembly sites are as follows.

### **Material Differences:**

	TI Taiwan	TI Malaysia
Mold compound	4221499	4211880

## Package Symbolization:

	Current	New				
TI Bug	Include	Replace with "TI" text				
Pin 1 ID	Stripe	Dot				
**ECAT	Include Value	Remove				
Example	212220	11.22CH7FK • 212228				

\*\* - Not all devices have ECAT information included in the symbolization, but for the ones that do, this information will be removed.

#### Reason for Change:

Continuity of Supply

Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

<b>D</b> 112	DEAGU		750 60 474								
RoHS	REACH	Green Status	IEC 62474								
🛛 No Change	🛛 🛛 No Change	🛛 No Change	🛛 No Change								
Changes to product identification resulting from this PCN:											
Assembly Site											
TI Taiwan Assembly Site Origin (22L) ASO: TAI											
TI Malaysia	Assembly Site Origin (22	L) ASO: MLA									
TEXAS INSTRUMENTS MADE IN: Malaysia 20C: 20: MSL '2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04 OPT: ITEM: 39 LBL: 5A (L)T0:1750 Product Affected:	(Q) 2	N74LSO7NSR 000 (d) 0336 07: 3959047MLA KY(1T) 7523483S12 (V) 0033317 so: she (21L) 0033317									
Froduct Affected.			I								
SN21220ADR	UCC21220AD	UCC21220D	UCC21222D								
SN21220DR	UCC21220ADR	UCC21220DR	UCC21222DR								

# Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approved 25-Jan-2023

# **Qualification Results**

Data Displayed as: Number of lots / Total sample size / Total failed

Туре		Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: UCC21222QDRQ1	Qual Device: UCC21220ADR	Qual Device: UCC21222QDRQ1	Qual Device: UCC21220ADR	QBS Reference: ISO6721BQDRQ1	QBS Reference: UCC23513QDWYQ1	QBS Reference: ISO7741FEDWRQ1
Test Group	A - Acce	lerated Environ	ment St	ress Tes	sts									
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL1 260C	1 Step	-	-	-	-	No Fails	-	-
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL2 260C	1 Step	No Fails	-	No Fails	-	-	-	-
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	1/77/0	-	-	-	3/231/0		
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours	1/77/0	-	-	-	3/231/0	-	-
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	3/231/0	-	1/77/0	-	3/231/0	-	-
PTC	A5	JEDEC JESD22- A105	1	45	PTC	-40/125C	1000 Cycles	1/45/0	-	-	-	-	-	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	1000 Hours	1/77/0	-	-	-	-	-	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	500 Hours	-	-	-	-	3/135/0	-	-
Test Group	B - Acce	lerated Lifetime	Simula	tion Tes	ts									
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	125C	1000 Hours		-	-	-	3/231/0	3/231/0	
HTOL	В1	JEDEC JESD22- A108	1	77	Life Test	150C	1000 Hours	-	-	-	-	-	-	3/231/0
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	125C	48 Hours	-	-	-	-	-	3/2400/0	-
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	150C	48 Hours	-	-	-	-	-	-	3/2400/0
Test Group	C - Pack	age Assembly I	integrity	Tests										
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	-	1/30/0	-	3/228/0	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	-	1/30/0	-	3/228/0	-	-
SD	C3	JEDEC J- STD-002	1	15	PB Solderability	>95% Lead Coverage		-	-	-	-	1/15/0	-	-
SD	C3	JEDEC J- STD-002	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	-	-	1/15/0	-	-
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	3/30/0	-	1/10/0	-	3/30/0	-	-
Test Group I	D - Die Fi	abrication Relia	bility Te	sts										
ЕМ	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements				
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown		-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements				
нсі	D3	JESD60 & 28	-		Hot Carrier Injection			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements				
NBTI	D4	-	-		Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements				
SM	D5	-	-		Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements				

Test Group	Fest Group E - Electrical Verification Tests													
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	1/3/0	-	-	-	1/3/0	1/3/0	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	1/3/0	-	1/3/0	-	1/3/0	1/3/0	1/3/0
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0	-	-	-	1/6/0	1/6/0	1/6/0
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	1/30/0	-	1/30/0	-	3/90/0	3/90/0	3/90/0

QBS: Qual By Similarity

Qual Device UCC21222QDRQ1 is qualified at MSL3 260C

Qual Device UCC21220ADR is qualified at MSL2 260C

Qual Device UCC21222QDRQ1 is qualified at MSL3 260C

Qual Device UCC21220ADR is qualified at MSL2 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles **Ambient Operating Temperature by Automotive Grade Level:** 

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C

Grade 3 (or I) : -40C to +85C

E1 (TEST): Électrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold : HTOL, ED

Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: <u>http://www.ti.com/</u>

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail					
WW PCN Team	PCN ww admin team@list.ti.com					

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